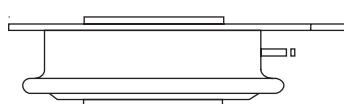


## Inverter Grade Thyristors (Hockey PUK Version), 330 A



TO-200AB (A-PUK)

### FEATURES

- Metal case with ceramic insulator
- All diffused design
- Center amplifying gate
- Guaranteed high dV/dt
- International standard case TO-200AB (A-PUK)
- Guaranteed high dI/dt
- High surge current capability
- Low thermal impedance
- High speed performance



### PRODUCT SUMMARY

$I_{T(AV)}$	330 A
-------------	-------

### TYPICAL APPLICATIONS

- Inverters
- Choppers
- Induction heating
- All types of force-commutated converters

### MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{T(AV)}$		330	A
	$T_{hs}$	55	°C
$I_{T(RMS)}$		610	A
	$T_{hs}$	25	°C
$I_{TSM}$	50 Hz	4680	A
	60 Hz	4900	
$I^2t$	50 Hz	110	$kA^2s$
	60 Hz	100	
$V_{DRM}/V_{RRM}$		1000 to 1200	V
$t_q$	Range	15 to 30	μs
$T_J$		- 40 to 125	°C

### ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	$V_{DRM}/V_{RRM}$ , MAXIMUM REPETITIVE PEAK VOLTAGE V	$V_{RSM}$ , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$I_{DRM}/I_{RRM}$ MAXIMUM AT $T_J = T_J$ MAXIMUM mA
ST173C..C	10	1000	1100	40
	12	1200	1300	

# ST173CPBF Series



Vishay High Power Products Inverter Grade Thyristors  
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## CURRENT CARRYING CAPABILITY

FREQUENCY					UNITS	
50 Hz	760	660	1200	1030	5570	4920
400 Hz	730	590	1260	1080	2800	2460
1000 Hz	600	490	1200	1030	1620	1390
2500 Hz	350	270	850	720	800	680
Recovery voltage $V_r$	50		50		50	
Voltage before turn-on $V_d$	$V_{DRM}$		$V_{DRM}$		$V_{DRM}$	
Rise of on-state current $dI/dt$	50		-		-	A/ $\mu$ s
Heatsink temperature	40	55	40	55	40	55
Equivalent values for RC circuit	47/0.22		47/0.22		47/0.22	$\Omega/\mu$ F

## ON-STATE CONDUCTION

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current at heatsink temperature	$I_{T(AV)}$	180° conduction, half sine wave double side (single side) cooled		330 (120)	A
				55 (85)	°C
Maximum RMS on-state current	$I_{T(RMS)}$	DC at 25 °C heatsink temperature double side cooled		610	
Maximum peak, one half cycle, non-repetitive surge current	$I_{TSM}$	$t = 10 \text{ ms}$	No voltage reapplied	4680	A
		$t = 8.3 \text{ ms}$		4900	
		$t = 10 \text{ ms}$	100 % $V_{RRM}$ reapplied	3940	
		$t = 8.3 \text{ ms}$		4120	
Maximum $I^2t$ for fusing	$I^2t$	$t = 10 \text{ ms}$	No voltage reapplied	110	kA <sup>2</sup> s
		$t = 8.3 \text{ ms}$		100	
		$t = 10 \text{ ms}$	100 % $V_{RRM}$ reapplied	77	
		$t = 8.3 \text{ ms}$		71	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1 \text{ to } 10 \text{ ms}$ , no voltage reapplied		1100	kA <sup>2</sup> /s
Maximum peak on-state voltage	$V_{TM}$	$I_{TM} = 600 \text{ A}$ , $T_J = T_J$ maximum, $t_p = 10 \text{ ms}$ sine wave pulse		2.07	
Low level value of threshold voltage	$V_{T(TO)1}$	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum		1.55	V
High level value of threshold voltage	$V_{T(TO)2}$	$(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum		1.61	
Low level value of forward slope resistance	$r_{t1}$	$(16.7 \% \times \pi \times I_{T(AV)} < I < \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum		0.87	mΩ
High level value of forward slope resistance	$r_{t2}$	$(I > \pi \times I_{T(AV)})$ , $T_J = T_J$ maximum		0.77	
Maximum holding current	$I_H$	$T_J = 25 \text{ °C}$ , $I_T > 30 \text{ A}$		600	mA
Typical latching current	$I_L$	$T_J = 25 \text{ °C}$ , $V_A = 12 \text{ V}$ , $R_a = 6 \Omega$ , $I_G = 1 \text{ A}$		1000	

## SWITCHING

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum non-repetitive rate of rise of turned on current	$dl/dt$	$T_J = T_J$ maximum, $V_{DRM}$ = Rated $V_{DRM}$ , $I_{TM} = 2 \times dl/dt$		1000	A/ $\mu$ s
Typical delay time	$t_d$	$T_J = 25 \text{ °C}$ , $V_{DM}$ = Rated $V_{DRM}$ , $I_{TM} = 50 \text{ A DC}$ , $t_p = 1 \mu\text{s}$ Resistive load, gate pulse: 10 V, 5 Ω source		1.1	
Maximum turn-off time	$t_q$	$T_J = T_J$ maximum, $I_{TM} = 300 \text{ A}$ , commutating $dl/dt = 20 \text{ A}/\mu\text{s}$		15	$\mu$ s
		$V_R = 50 \text{ V}$ , $t_p = 500 \mu\text{s}$ , $dV/dt$ : See table in device code		30	



# ST173CPBF Series

Inverter Grade Thyristors Vishay High Power Products  
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BLOCKING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to 80 % $V_{DRM}$ , higher value available on request		500	V/ $\mu$ s
Maximum peak reverse and off-state leakage current	$I_{RRM}$ , $I_{DRM}$	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied		40	mA

TRIGGERING					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum, $f = 50$ Hz, $d\% = 50$		60	W
Maximum average gate power	$P_{G(AV)}$			10	
Maximum peak positive gate current	$I_{GM}$	$T_J = T_J$ maximum, $t_p \leq 5$ ms		10	A
Maximum peak positive gate voltage	+ $V_{GM}$			20	V
Maximum peak negative gate voltage	- $V_{GM}$			5	
Maximum DC gate current required to trigger	$I_{GT}$	$T_J = 25$ °C, $V_A = 12$ V, $R_a = 6$ Ω		200	mA
Maximum DC gate voltage required to trigger	$V_{GT}$			3	V
Maximum DC gate current not to trigger	$I_{GD}$			20	mA
Maximum DC gate voltage not to trigger	$V_{GD}$	$T_J = T_J$ maximum, rated $V_{DRM}$ applied		0.25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum operating junction temperature range	$T_J$			- 40 to 125	°C
Maximum storage temperature range	$T_{Stg}$			- 40 to 150	
Maximum thermal resistance, junction to heatsink	$R_{thJ-hs}$	DC operation single side cooled		0.17	K/W
		DC operation double side cooled		0.08	
Maximum thermal resistance, case to heatsink	$R_{thC-hs}$	DC operation single side cooled		0.033	
		DC operation double side cooled		0.017	
Mounting force, ± 10 %				4900 (500)	N (kg)
Approximate weight				50	g
Case style		See dimensions - link at the end of datasheet		TO-200AB (A-PUK)	

$\Delta R_{thJ-hs}$ CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION		RECTANGULAR CONDUCTION		TEST CONDITIONS	UNITS
	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE		
180°	0.015	0.016	0.011	0.011	$T_J = T_J$ maximum	K/W
120°	0.018	0.019	0.019	0.019		
90°	0.024	0.024	0.026	0.026		
60°	0.035	0.035	0.036	0.037		
30°	0.060	0.060	0.060	0.061		

#### Note

- The table above shows the increment of thermal resistance  $R_{thJ-hs}$  when devices operate at different conduction angles than DC

# ST173CPBF Series

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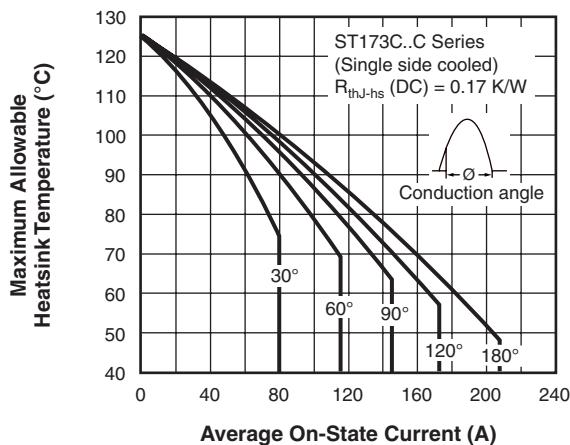


Fig. 1 - Current Ratings Characteristics

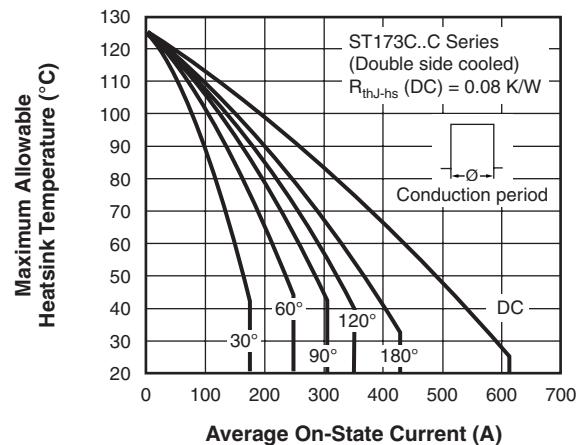


Fig. 4 - Current Ratings Characteristics

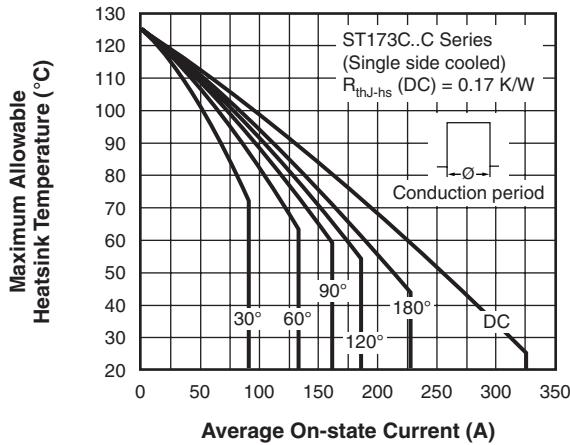


Fig. 2 - Current Ratings Characteristics

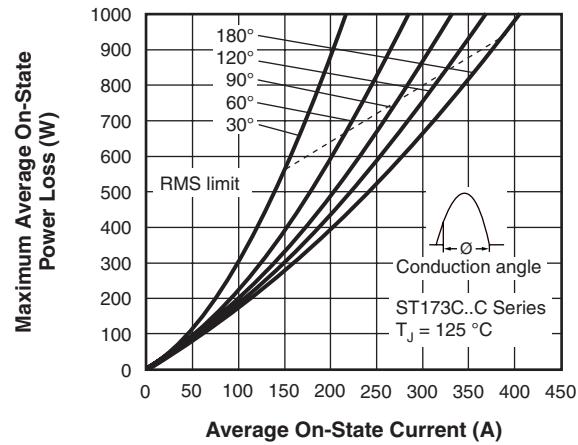


Fig. 5 - On-State Power Loss Characteristics

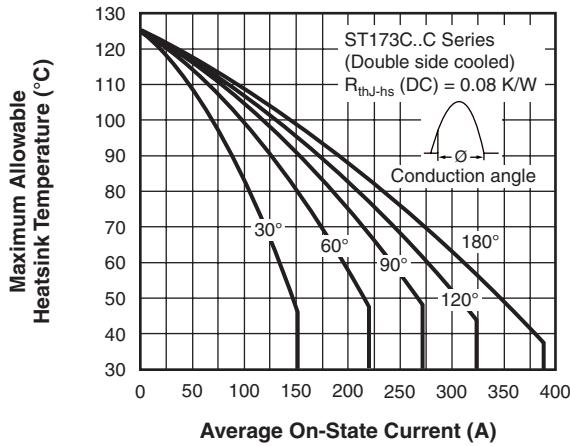


Fig. 3 - Current Ratings Characteristics

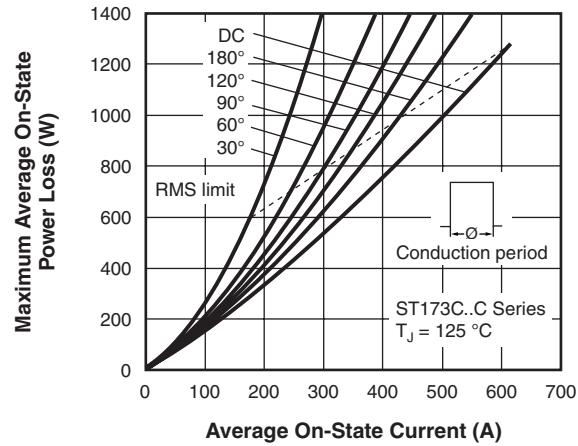


Fig. 6 - On-State Power Loss Characteristics

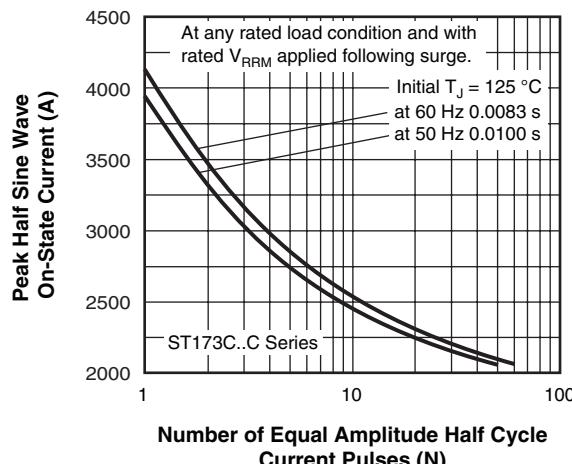


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

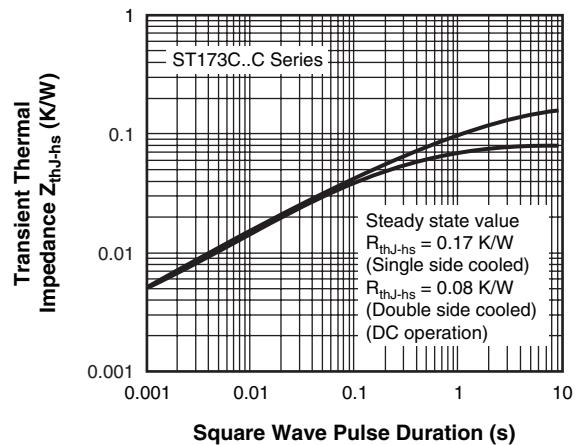
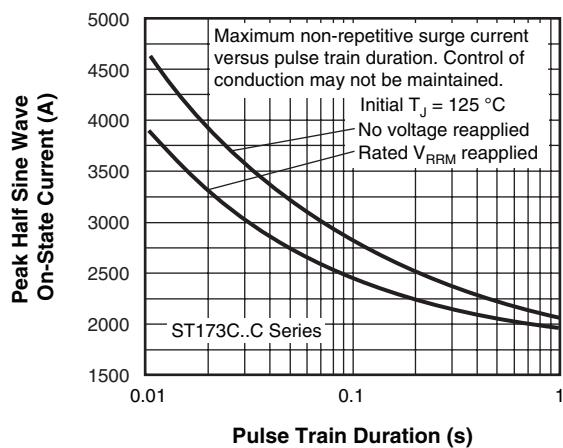

 Fig. 10 - Thermal Impedance  $Z_{thJ-hs}$  Characteristics


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

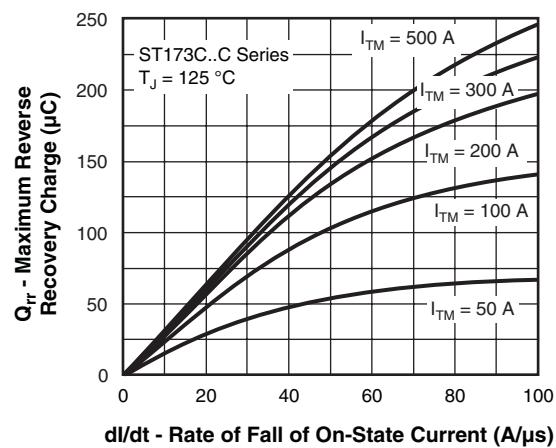


Fig. 11 - Reverse Recovered Charge Characteristics

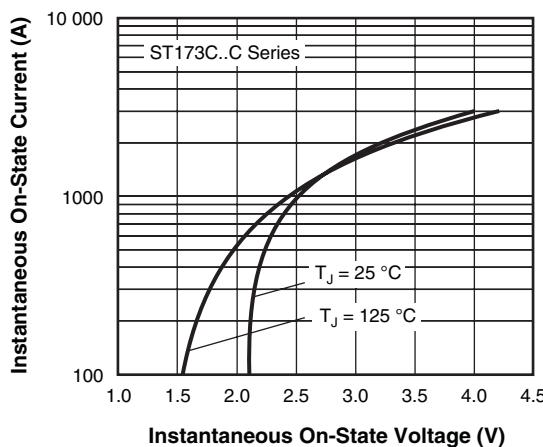


Fig. 9 - On-State Voltage Drop Characteristics

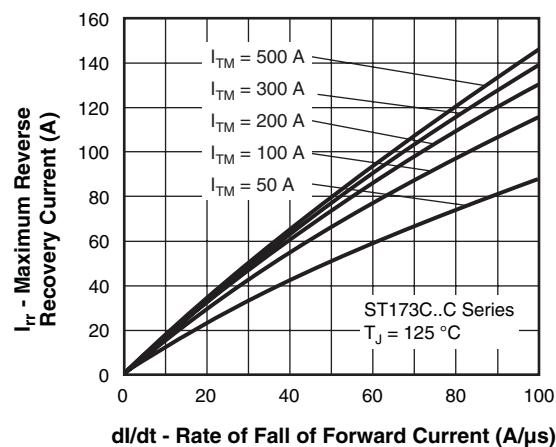


Fig. 12 - Reverse Recovered Current Characteristics

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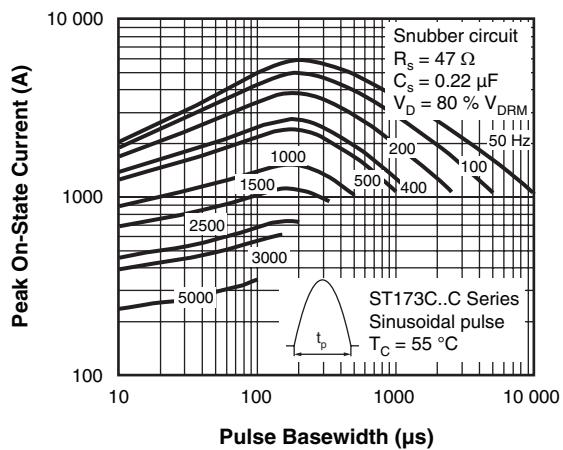
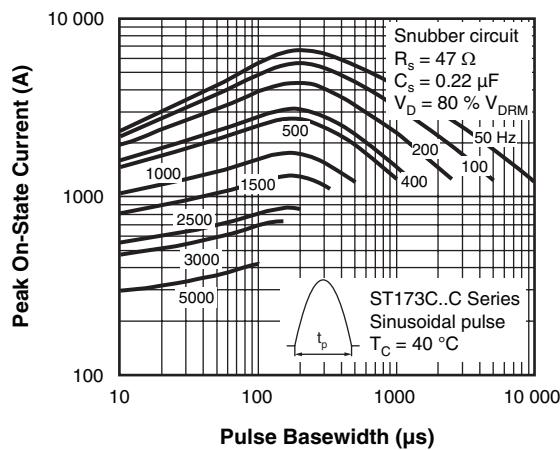


Fig. 13 - Frequency Characteristics

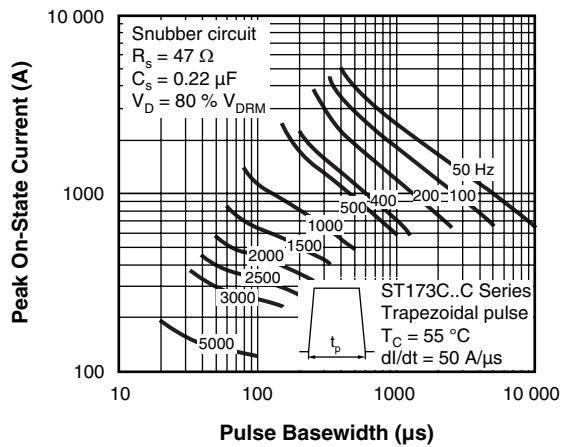
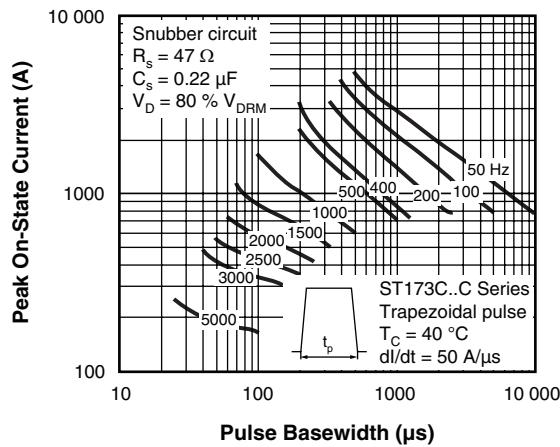


Fig. 14 - Frequency Characteristics

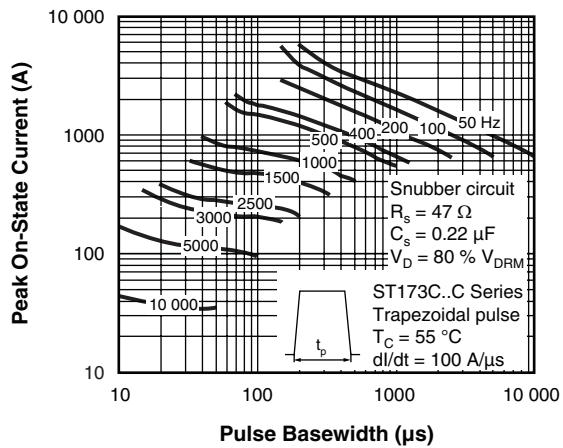
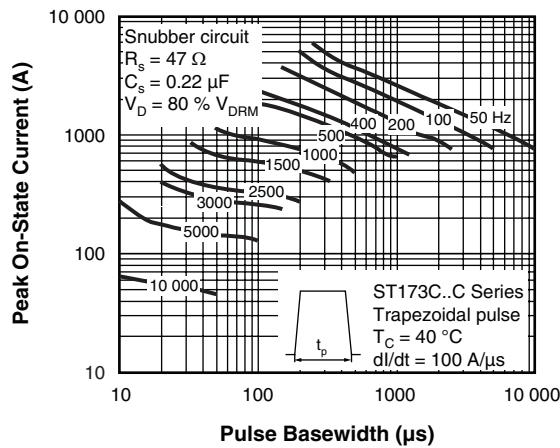


Fig. 15 - Frequency Characteristics

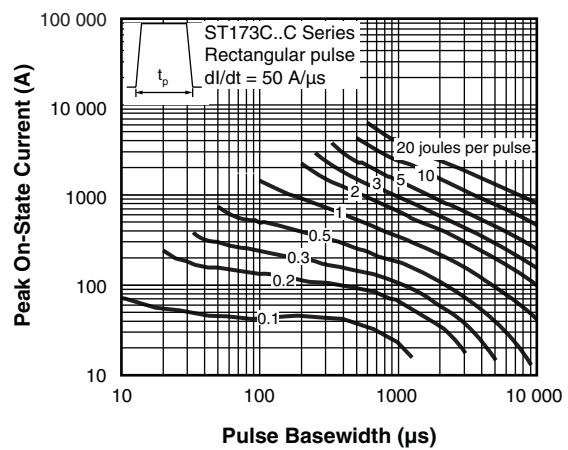
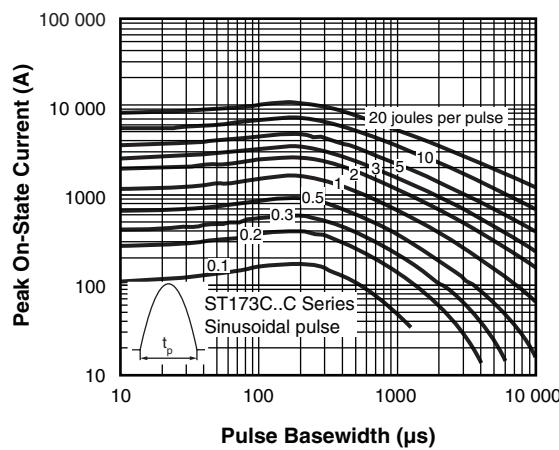


Fig. 16 - Maximum On-State Energy Power Loss Characteristics

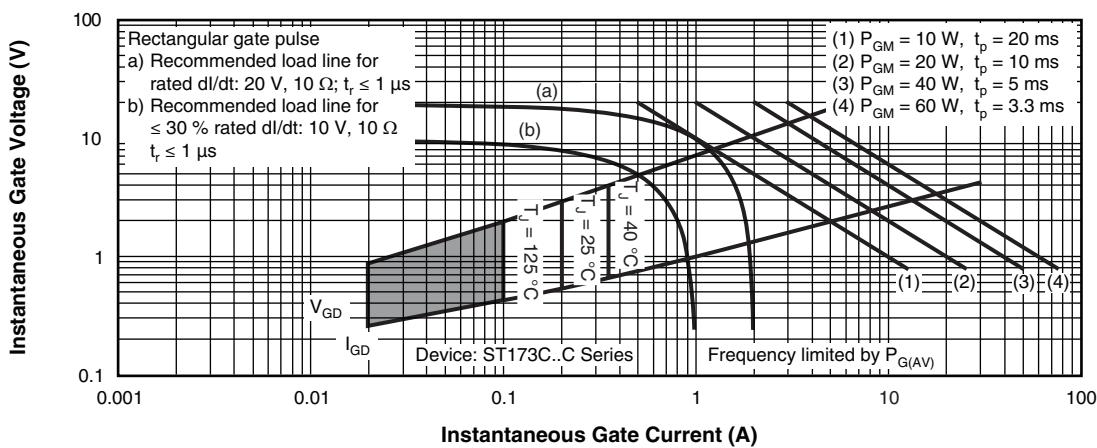


Fig. 17 - Gate Characteristics

# ST173CPBF Series

Vishay High Power Products Inverter Grade Thyristors  
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## ORDERING INFORMATION TABLE

Device code	ST	17	3	C	12	C	H	K	1	-	P
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)	(10)	(11)

- 1** - Thyristor
- 2** - Essential part number
- 3** - 3 = Fast turn-off
- 4** - C = Ceramic PUK
- 5** - Voltage code x 100 =  $V_{RRM}$  (see Voltage Ratings table)
- 6** - C = PUK case TO-200AB (A-PUK)
- 7** - Reapplied dV/dt code (for  $t_q$  test condition)
- 8** -  $t_q$  code \_\_\_\_\_
- 9** - 0 = Eyelet terminals  
(gate and aux. cathode unsoldered leads)  
1 = Fast-on terminals  
(gate and aux. cathode unsoldered leads)  
2 = Eyelet terminals  
(gate and aux. cathode soldered leads)  
3 = Fast-on terminals  
(gate and aux. cathode soldered leads)
- 10** - Critical dV/dt:
  - None = 500 V/ $\mu$ s (standard value)
  - L = 1000 V/ $\mu$ s (special selection)
- 11** - P = Lead (Pb)-free

dV/dt - $t_q$ combinations available						
dV/dt (V/ $\mu$ s)	20	50	100	<b>200</b>	400	
$t_q$ ( $\mu$ s)	15	CL	--	--	--	--
	18	CP	DP	EP	<b>FP*</b>	--
	20	CK	DK	EK	<b>FK*</b>	HK
	25	CJ	DJ	EJ	FJ	HJ
	30	--	DH	EH	FH	HH

\* Standard part number.

All other types available only on request.

LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95074">http://www.vishay.com/doc?95074</a>



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